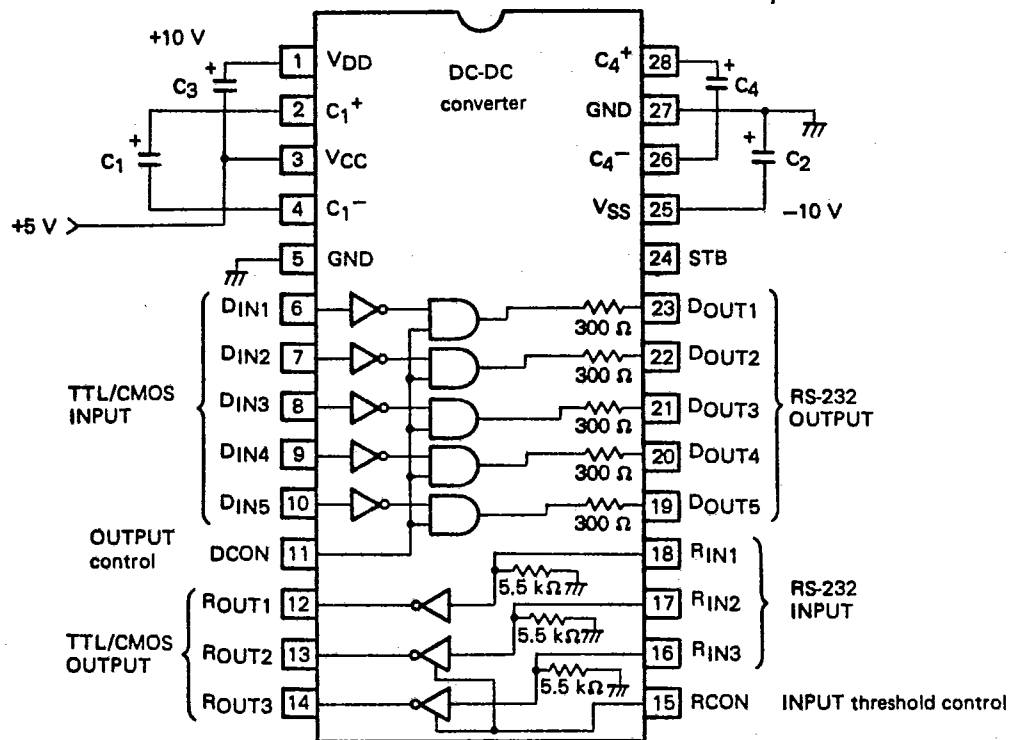


BLOCK DIAGRAM/CONNECTION DIAGRAM (Top View)



* STB terminal is pulled down to ground by internal resistor.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Supply Voltage	V_{CC}	-0.5 to +6.0	V
Driver Input Voltage	D_{IN}	-0.5 to $V_{CC} + 0.5$	V
Receiver Input Voltage	R_{IN}	-30.0 to +30.0	V
Driver Output Voltage	D_{OUT}	-25.0 to +25.0 Note 1	V
Receiver Output Voltage	R_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input Current	I_{IN}	± 60.0	mA
Operating Temperature Range	T_{OPT}	-40 to +85	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$
Power Dissipation	P_T	0.5	W

Note 1 Pulse width 1 ms, duty 10 % MAX.

RECOMMENDED OPERATING CONDITION

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
Operating Temperature Range	T_{OPT}	-20		80	$^\circ\text{C}$
External Capacitor Note 2		22		47	μF

Note 2 The electrolytic capacitor's capacitance goes smaller, when ambient temperature is below 0°C . Take the lowest operating temperature into account when choosing the capacitance value. Connect the external capacitor to minimize the wiring between the capacitor and the pin of μPD4715 .

ELECTRICAL CHARACTERISTICS (Total)

($V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$, C_1 to $C_4 = 22\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Supply Current	I_{CC}		9.0	18	mA	$V_{CC}=+5\text{ V}$, $R_L=\infty$, STB=GND or OPEN
Supply Current (Standby)	$I_{CC}(\text{Standby})$		50	100	μA	$V_{CC}=+5\text{ V}$, $R_L=\infty$, STB=+5 V Note 3
Input Capacitance	C_{IN}			10	pF	Driver and Receiver Input

Note 3 When high level voltage is applied to STB terminal, internal DC-DC converter stops and Dout, Rout terminals go to high impedance.

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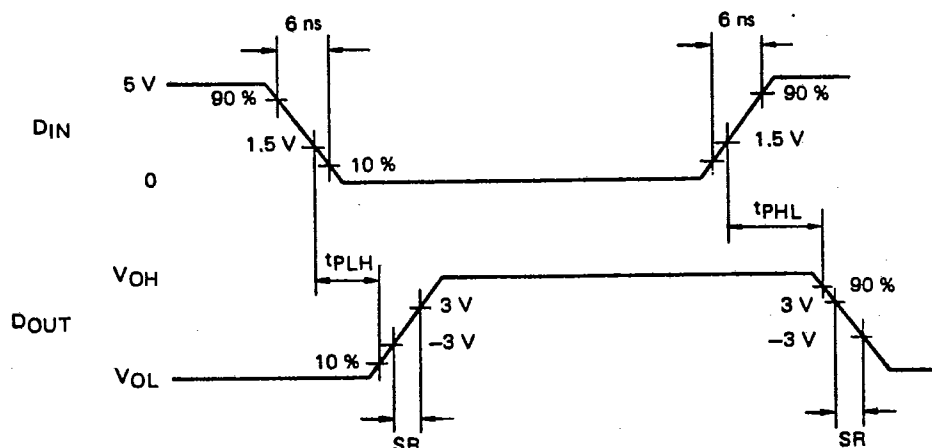
ELECTRICAL CHARACTERISTIC (Driver)

(VCC = +5.0 V $\pm$ 10 %, T_a = -40 °C to +85 °C, C₁ to C₄ = 22 μ F)

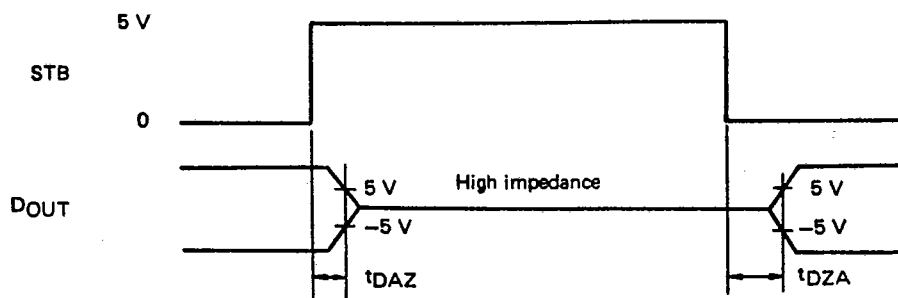
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Low Level Input Voltage	V _{IL}			0.8	V	
High Level Input Voltage	V _{IH}	2.0			V	
Low Level Input Current	I _{IL}	0		-1.0	μ A	
High Level Input Current	I _{IH}	0		1.0	μ A	
Output Voltage	V _{DO}		± 9.7		V	V _{CC} =5.0 V, R _L = ∞ , T _a =25 °C
		± 6.5	+7.7, -7.2		V	V _{CC} =5.0 V, R _L =3 k Ω , T _a =25 °C
		± 5			V	V _{CC} =5.0 V, R _L =3 k Ω , T _a =T _{opt}
		± 6			V	V _{CC} =4.5 V, R _L =3 k Ω , T _a =25 °C
Output Short Current	I _{SC}		± 15	± 40	mA	V _{CC} =5.0 V, to GND
Slew Rate Note 5	SR	1.5	4	30	V/ μ s	C _L =10 pF, R _L =3 ~ 7 k Ω
		1.5	4		V/ μ s	C _L =2 500 pF, R _L =3 ~ 7 k Ω
Propagation Delay Note 5	t _{PHL}		0.8		μ s	R _L =3.5 k Ω , C _L =2 500 pF
	t _{PLH}				μ s	
Output Resistance	R _O	300			Ω	V _{CC} =V _{DD} =V _{SS} =0 V, V _{OUT} = ± 2 V
Transition Time Note 6	t _{DAZ}			1	μ s	
Transition Time Note 6	t _{DZA}			10	ms	

Note 4 The outputs of the five driver circuits can be fixed to the OFF (Low) status, independently of data signals, by lowering the signal level of the output control pin (D con terminal).

Note 5 Measurement Point.



Note 6 Measurement Point.



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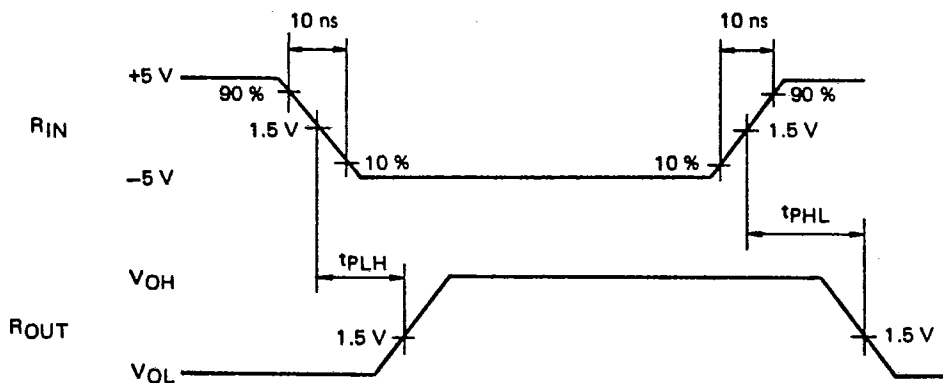
ELECTRICAL CHARACTERISTIC (Receiver)

(V_{CC} = +5.0 V ± 10 %, T_a = -40 °C to +85 °C, C₁ to C₄ = 22 μF)

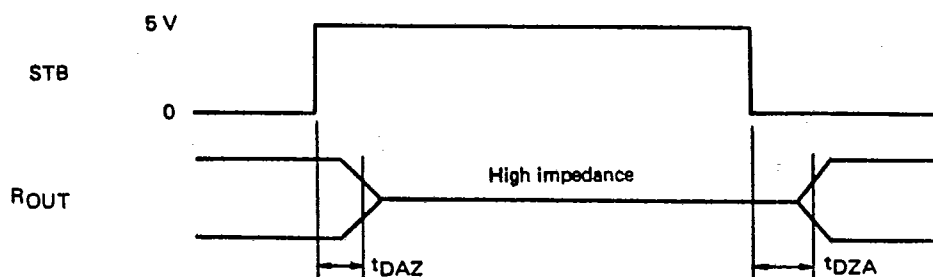
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Low Level Output Voltage	V _{OL}			0.4	V	I _{OUT} =4 mA
High Level Output Voltage	V _{OH}	V _{CC} -0.8			V	I _{OUT} =-4 mA
Output Capacitance Load	C _L			150	pF	
Propagation Delay Note 8	t _{PHL} t _{PLH}		0.1		μs	R _L =1 kΩ, C _L =100 pF
Input Current	I _{IN}		0.9		mA	V _{IN} = ±5 V
Input Resistance	R _I	3	5.5	7	kΩ	V _{IN} = ±3 V to ±25 V
Input Voltage	V _{IN}	-30		+30	V	
Input Open Voltage	V _{IO}			0.5	V	Only Input Threshold TYPE A
Input Threshold TYPE A (RCON: Low)	V _{IH}	1.6	2.2	2.6	V	V _{CC} =+5 V
	V _{IL}	0.6	1	1.6	V	V _{CC} =+5 V
	V _H	0.5	1.2	1.5	V	V _{CC} =+5 V (Hysteresis width)
Input Threshold TYPE B (RCON: High) Note 7	V _{IH}	1.6	2.2	2.6	V	V _{CC} =+5 V
	V _{IL}	-0.4	-1.8	-3.0	V	V _{CC} =+5 V
	V _H	2.6	4.0	5.4	V	V _{CC} =+5 V (Hysteresis width)
Transition Time Note 9	t _{DAZ}			1	μs	
Transition Time Note 9	t _{DZA}			10	ms	

Note 7 Applied to only receiver 2.3.

Note 8 Measurement Point.



Note 9 Measurement Point.

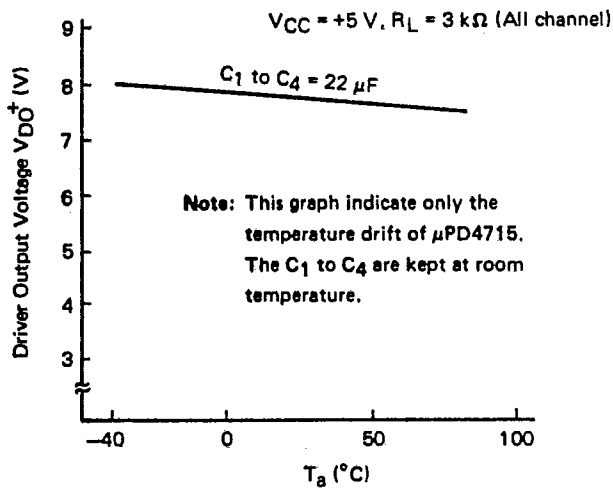


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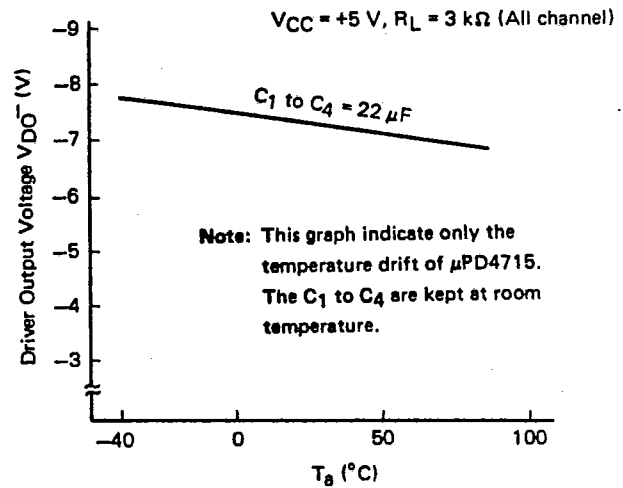
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

T-75-45-05

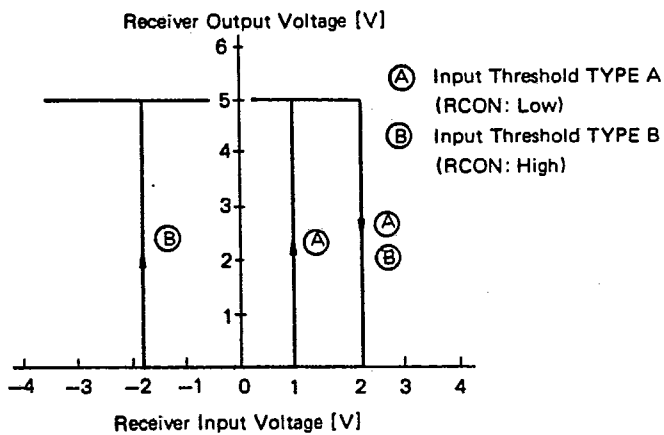
Driver Output Voltage $V_{DO}^+ - T_a$



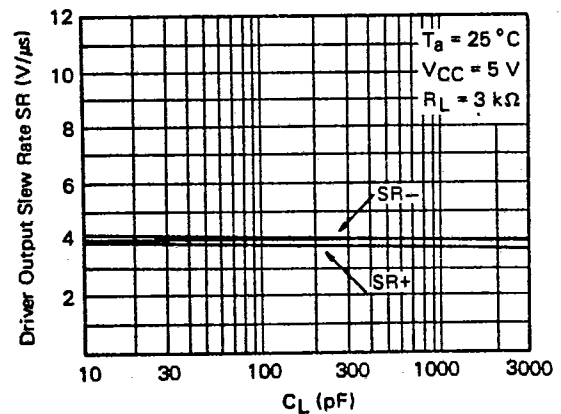
Driver Output Voltage $V_{DO}^- - T_a$



Receiver Input Hysteresis



Driver Output Slew Rate - C_L

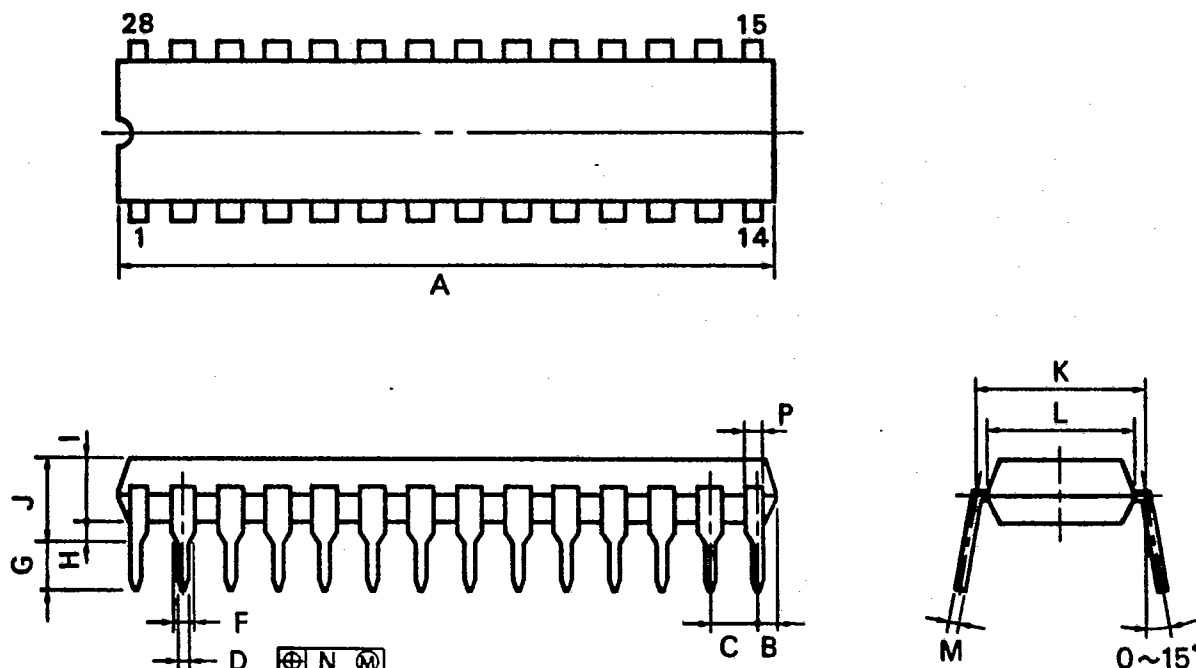


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PACKAGE DIMENSION

28PIN PLASTIC DIP (400 mil)

T-75-45-05



P28C-100-400

NOTES

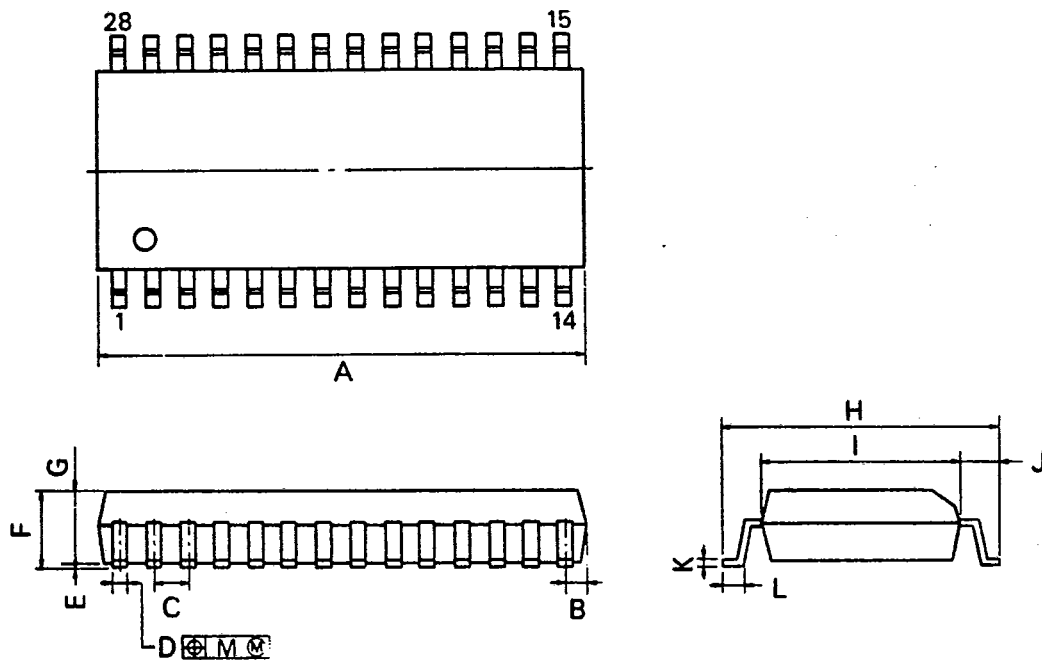
- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
A	35.56 MAX.	1.400 MAX.
B	1.27 MAX.	0.050 MAX.
C	2.54 (T.P.)	0.100 (T.P.)
D	0.50 ±0.10	0.020 ^{+0.004} / _{-0.008}
F	1.1 MIN.	0.043 MIN.
G	3.5 ±0.3	0.138 ±0.012
H	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.72 MAX.	0.226 MAX.
K	10.16 (T.P.)	0.400 (T.P.)
L	8.6	0.339
M	0.25 ^{+0.10} / _{-0.08}	0.010 ^{+0.004} / _{-0.003}
N	0.25	0.01
P	0.9 MIN.	0.035 MIN.

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28PIN PLASTIC SOP (375 mil)

T-75-45-05



P28GM-50-375B

NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	18.07 MAX.	0.712 MAX.
B	0.78 MAX.	0.031 MAX.
C	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
E	$0.1^{+0.1}_{-0.0}$	$0.004^{+0.004}_{-0.000}$
F	2.9 MAX.	0.115 MAX.
G	2.50	0.098
H	$10.3^{+0.3}_{-0.0}$	$0.406^{+0.012}_{-0.013}$
I	7.2	0.283
J	1.6	0.063
K	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.002}$
L	$0.8^{+0.2}_{-0.0}$	$0.031^{+0.008}_{-0.008}$
M	0.12	0.005